



Fast Recovery Diode

Types M2325HA400 and M2325HA450

Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V _{RRM}	Repetitive peak reverse voltage, (note 1)	4000-4500	V
V _{RSM}	Non-repetitive peak reverse voltage, (note 1)	4100-4600	V

	OTHER RATINGS (note 6)	MAXIMUM LIMITS	UNITS
I _{F(AV)}	Mean forward current, T _{sink} =55°C, (note 2)	2325	A
I _{F(AV)}	Mean forward current. T _{sink} =100°C, (note 2)	1550	A
I _{F(AV)}	Mean forward current. T _{sink} =100°C, (note 3)	775	A
I _{F(RMS)}	Nominal RMS forward current, T _{sink} =25°C, (note 2)	4330	A
I _{F(d.c.)}	D.C. forward current, T _{sink} =25°C, (note 4)	3820	A
I _{FSM}	Peak non-repetitive surge t _p =10ms, V _{RM} =0.6V _{RRM} , (note 5)	28.0	kA
I _{FSM2}	Peak non-repetitive surge t _p =10ms, V _{RM} ≤10V, (note 5)	30.8	kA
I ² t	I ² t capacity for fusing t _p =10ms, V _{RM} =0.6V _{RRM} , (note 5)	3.92×10 ⁶	A ² s
I ² t	I ² t capacity for fusing t _p =10ms, V _{RM} ≤10V, (note 5)	4.74×10 ⁶	A ² s
T _{HS}	Operating temperature range	-40 to +150	°C
T _{stg}	Storage temperature range	-40 to +150	°C

Notes:-

- 1) De-rating factor of 0.13% per °C is applicable for T_j below 25°C.
- 2) Double side cooled, single phase; 50Hz, 180° half-sinewave.
- 3) Single side cooled, single phase; 50Hz, 180° half-sinewave.
- 4) Double side cooled.
- 5) Half-sinewave, 150°C T_j initial.

Characteristics

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS (Note 1)	UNITS
V _{FM}	Maximum peak forward voltage	-	-	2.60	I _{FM} =2500A	V
V ₀	Threshold voltage	-	-	1.581		V
r _s	Slope resistance	-	-	0.402		mΩ
V _{FRM}	Maximum forward recovery voltage	-	-	115 75	di/dt = 1000A/μs di/dt = 1000A/μs, T _j =25°C	V
I _{RRM}	Peak reverse current	-	-	150	Rated V _{RRM}	mA
Q _{rr}	Reverse Recovery Charge	-	2400	2650		μC
Q _{ra}	Recovered charge, 50% Chord	-	1460	-	I _{FM} =1000A, t _p =500μs, di/dt=200A/μs,	μC
I _{rm}	Reverse Recovery Current	-	540	-	V _r =50V, 50% Chord.	A
t _{rr}	Reverse recovery time, 50% Chord	-	5.4	-		μs
R _{th(j-hs)}	Thermal resistance, junction to heatsink	-	-	0.0105 0.0173 0.0273	Double side cooled Anode side cooled Cathode side cooled	K/W
F	Mounting force	30	-	40		kN
W _t	Weight	-	1.2	-		kg

Notes:-

 1) Unless otherwise indicated T_j=150°C.

Notes on Ratings and Characteristics

1.0 Voltage Grade Table

Voltage Grade	V_{RRM} (V)	V_{RSM} (V)	V_R dc (V)
40	4000	4100	2000
45	4500	4600	2100

2.0 De-rating Factor

A blocking voltage de-rating factor of 0.13% per °C is applicable to this device for T_j below 25°C.

3.0 ABCD Constants

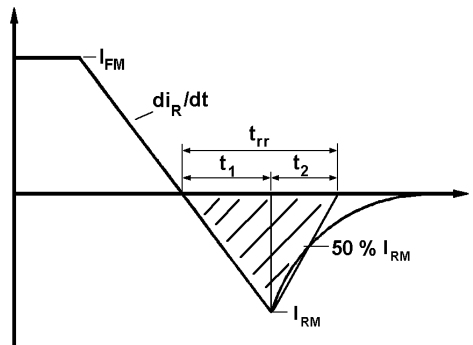
These constants (applicable only over current range of V_F characteristic in Figure 1) are the coefficients of the expression for the forward characteristic given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

where I_F = instantaneous forward current.

4.0 Reverse recovery ratings

(i) Q_{ra} is based on 50% I_{rm} chord as shown in Fig.(a) below.



(ii) Q_{rr} is based on a 150 μ s integration time.

i.e.

$$Q_{rr} = \int_0^{150\mu s} i_{rr} \cdot dt$$

(iii)

$$K \text{ Factor} = \frac{t_1}{t_2}$$

5.0 Reverse Recovery Loss

The following procedure is recommended for use where it is necessary to include reverse recovery loss.

From waveforms of recovery current obtained from a high frequency shunt (see Note 1) and reverse voltage present during recovery, an instantaneous reverse recovery loss waveform must be constructed. Let the area under this waveform be E joules per pulse. A new sink temperature can then be evaluated from:

$$T_{SINK} = T_{J(MAX)} - E \cdot [k + f \cdot R_{th(J-Hs)}]$$

Where $k = 0.2314$ ($^{\circ}\text{C/W}$)/s

E = Area under reverse loss waveform per pulse in joules (W.s.)

f = Rated frequency in Hz at the original sink temperature.

$R_{th(J-Hs)}$ = d.c. thermal resistance ($^{\circ}\text{C/W}$)

The total dissipation is now given by:

$$W_{(tot)} = W_{(original)} + E \cdot f$$

NOTE 1 - Reverse Recovery Loss by Measurement

This device has a low reverse recovered charge and peak reverse recovery current. When measuring the charge, care must be taken to ensure that:

(a) AC coupled devices such as current transformers are not affected by prior passage of high amplitude forward current.

(b) A suitable, polarised, clipping circuit must be connected to the input of the measuring oscilloscope to avoid overloading the internal amplifiers by the relatively high amplitude forward current signal.

(c) Measurement of reverse recovery waveform should be carried out with an appropriate critically damped snubber, connected across diode anode to cathode. The formula used for the calculation of this snubber is shown below:

$$R^2 = 4 \cdot \frac{V_r}{C_s \cdot di/dt}$$

Where: V_r = Commutating source voltage

C_s = Snubber capacitance

R = Snubber resistance

6.0 Computer Modelling Parameters

6.1 Device Dissipation Calculations

$$I_{AV} = \frac{-V_o + \sqrt{V_o^2 + 4 \cdot ff^2 \cdot r_s \cdot W_{AV}}}{2 \cdot ff^2 \cdot r_s}$$

Where $V_o = 1.581V$, $r_s = 0.402m\Omega$

ff = form factor (normally unity for fast diode applications)

$$W_{AV} = \frac{\Delta T}{R_{th}}$$

$$\Delta T = T_{j(MAX)} - T_{Hs}$$

6.2 Calculation of V_F using ABCD Coefficients

The forward characteristic I_F Vs V_F , on Fig. 1 is represented in two ways;

- (i) the well established V_o and r_s tangent used for rating purposes and
- (ii) a set of constants A, B, C, and D forming the coefficients of the representative equation for V_F in terms of I_F given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

The constants, derived by curve fitting software, are given in this report for hot characteristics. The resulting values for V_F agree with the true device characteristic over a current range, which is limited to that plotted.

	25°C Coefficients	150°C Coefficients
A	0.613793358	0.130022348
B	0.08838485	0.1168203
C	1.86534×10^{-4}	2.23322×10^{-4}
D	0.01669329	0.01995332

Curves

Figure 1 – Forward characteristics of Limit device

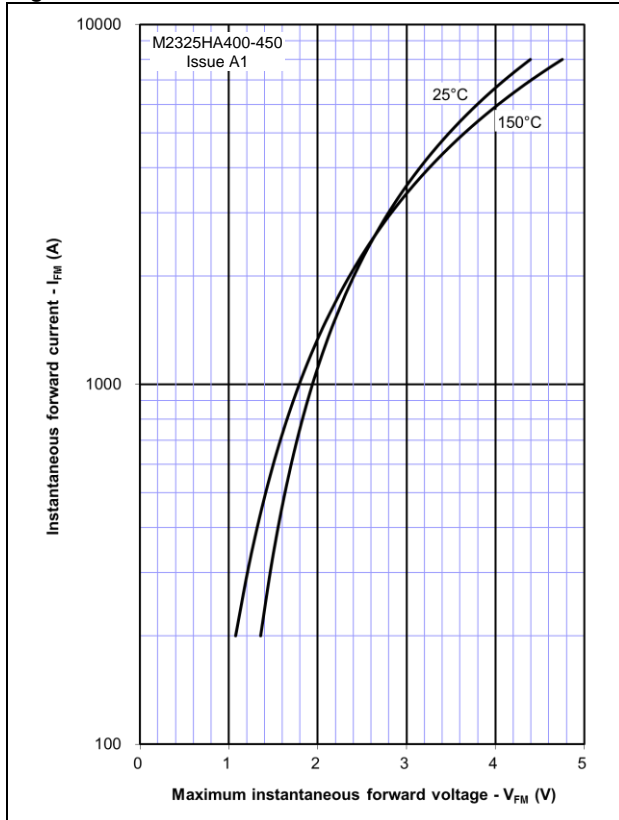


Figure 2 – Maximum forward recovery voltage

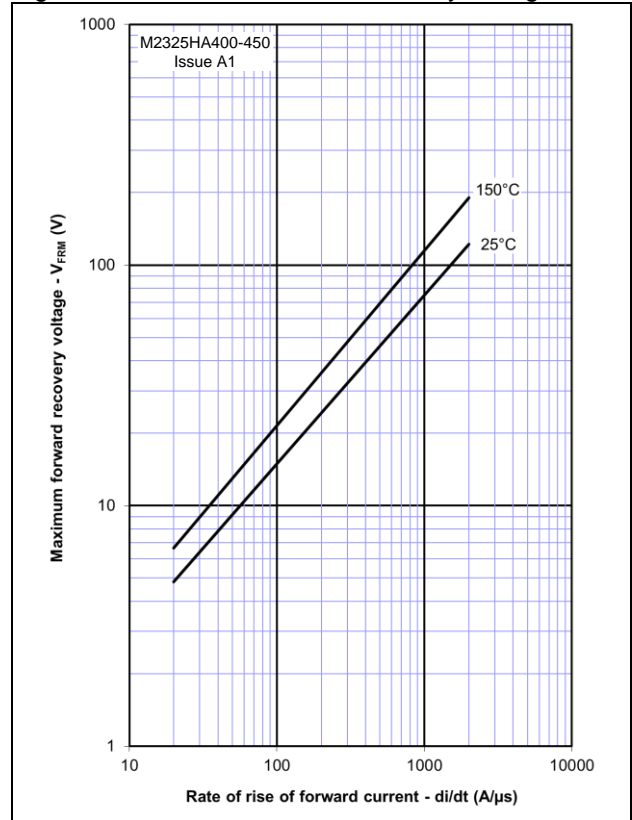


Figure 3 - Recovered charge, Q_{rr}

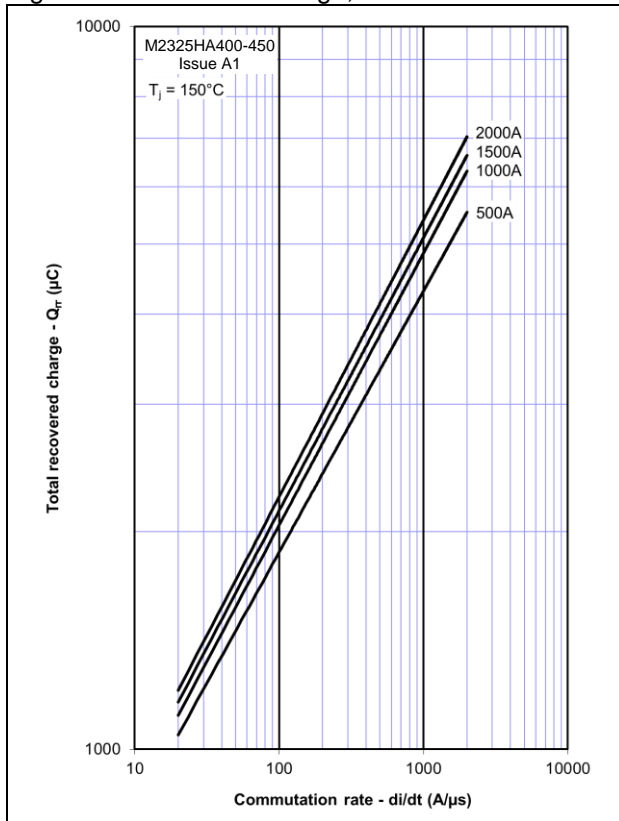


Figure 4 - Recovered charge, Q_{ra} (50% chord)

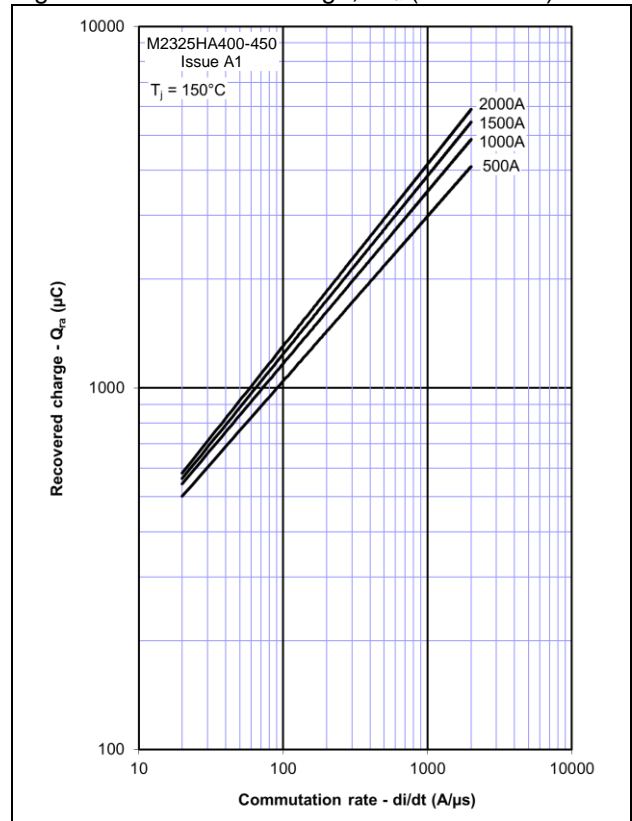


Figure 5 - Maximum reverse current, I_{rm}

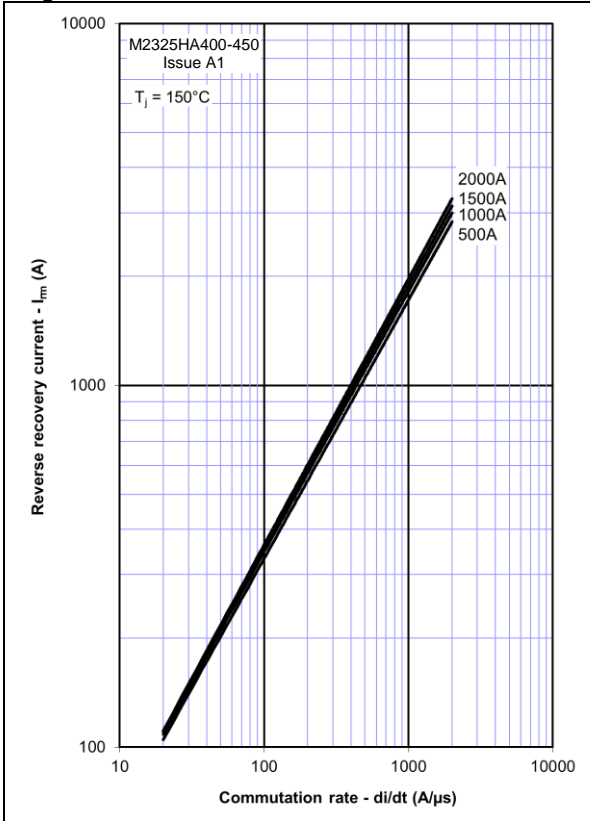


Figure 6 - Maximum recovery time, t_{rr} (50% chord)

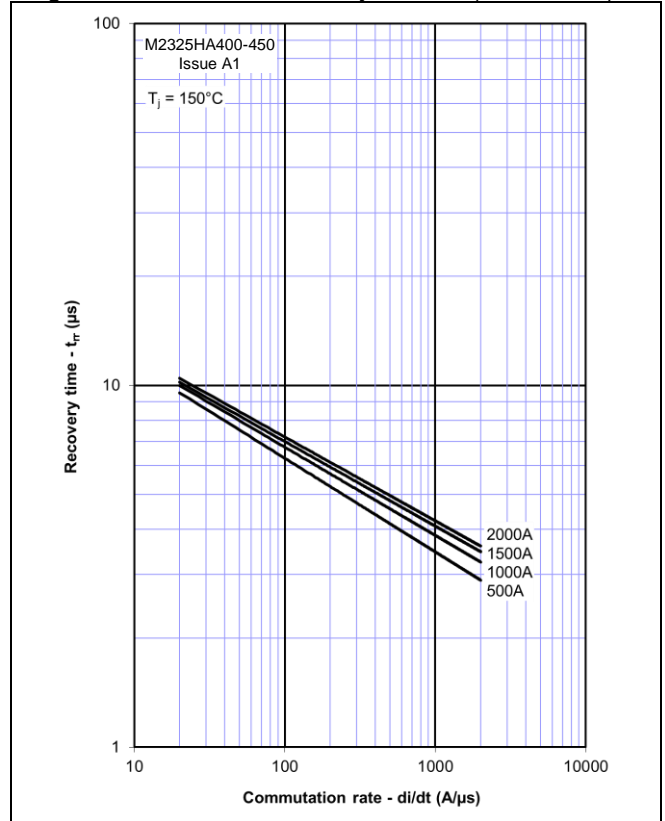


Figure 7 - Reverse recovery energy per pulse

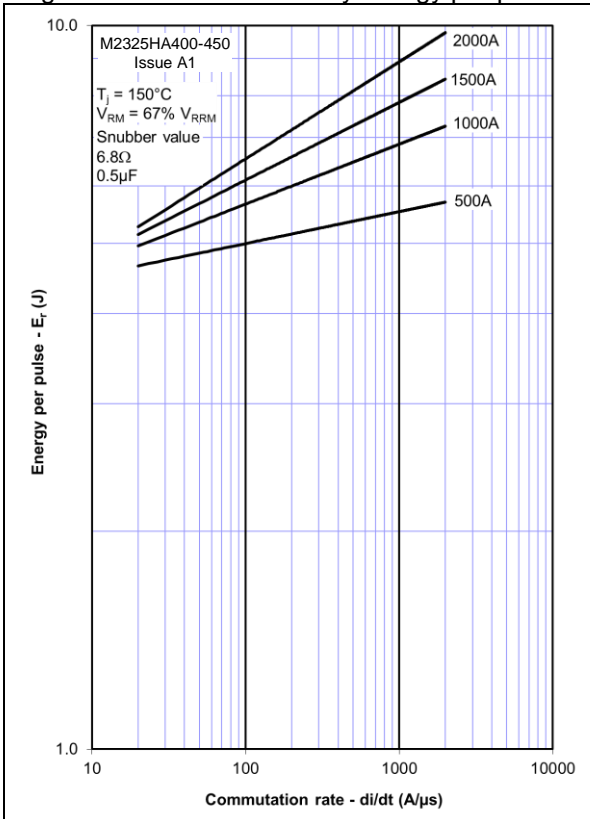


Figure 8 - Sine wave energy per pulse

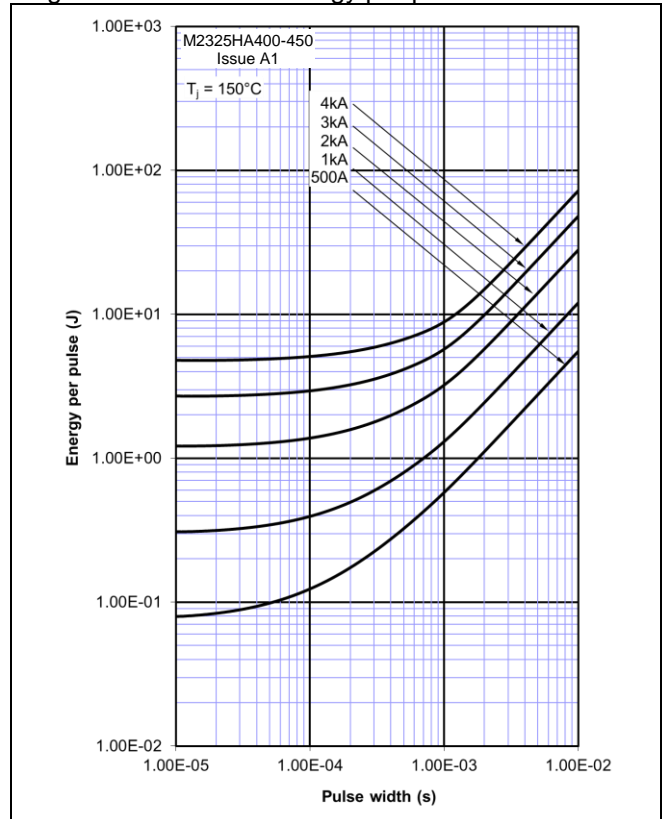


Figure 9 - Sine wave frequency vs. pulse width

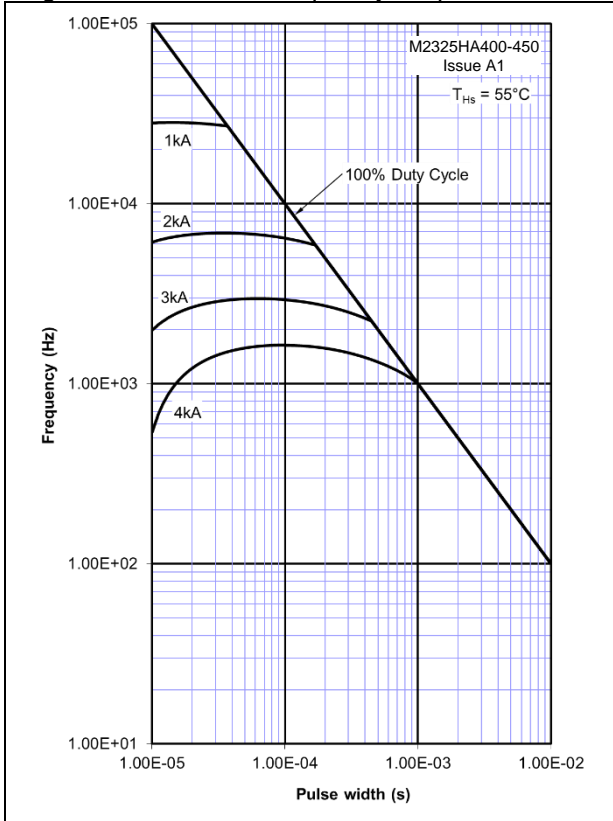


Figure 10 - Sine wave frequency vs. pulse width

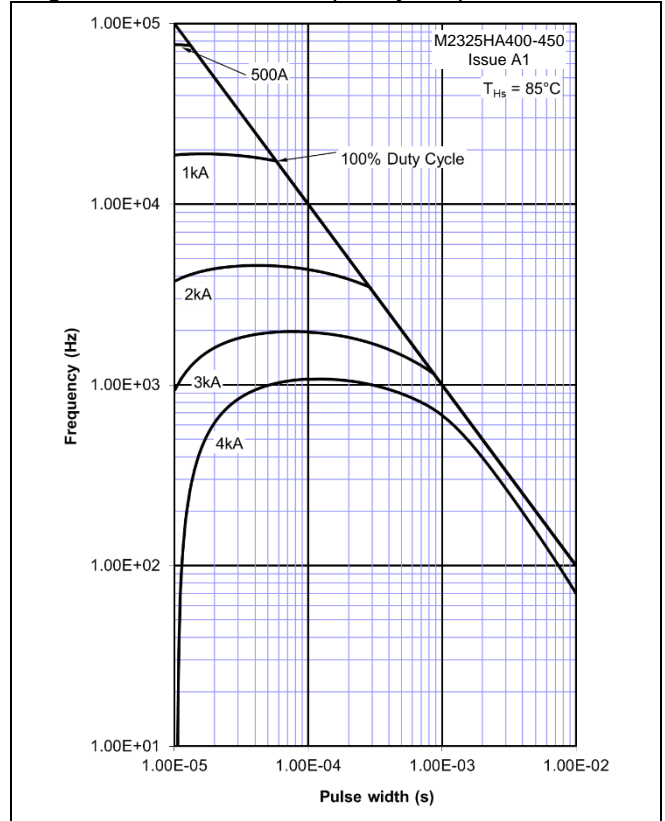


Figure 11 - Square wave frequency vs pulse width

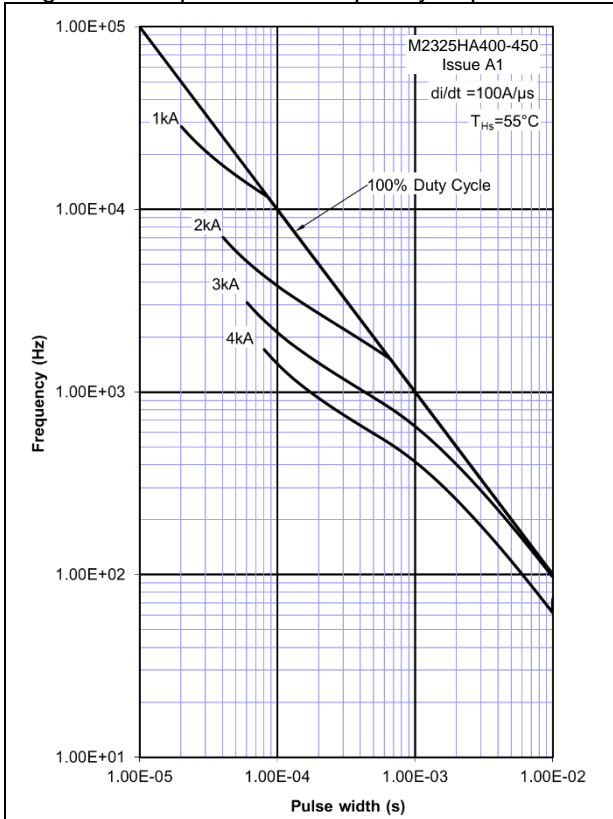


Figure 12 - Square wave frequency vs pulse width

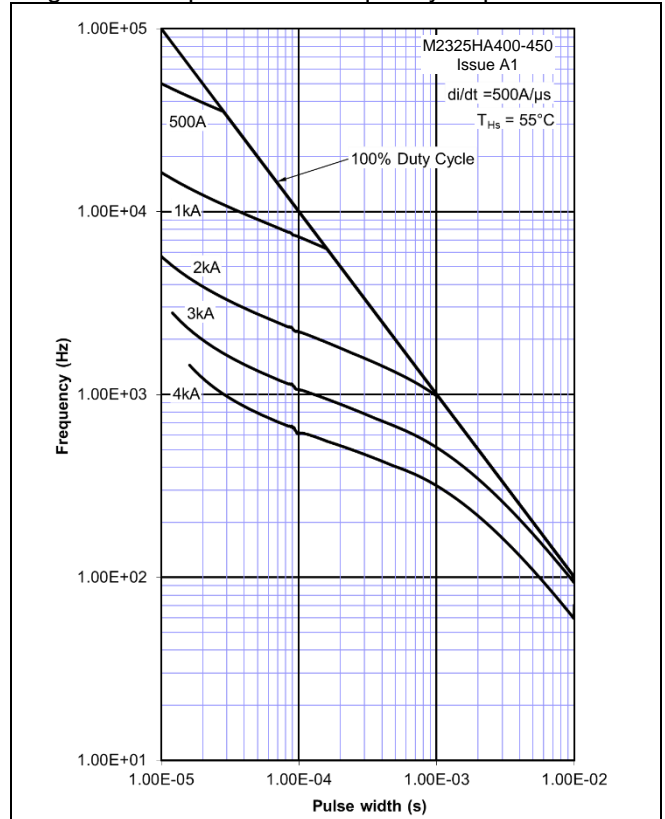


Figure 13 - Square wave frequency vs pulse width

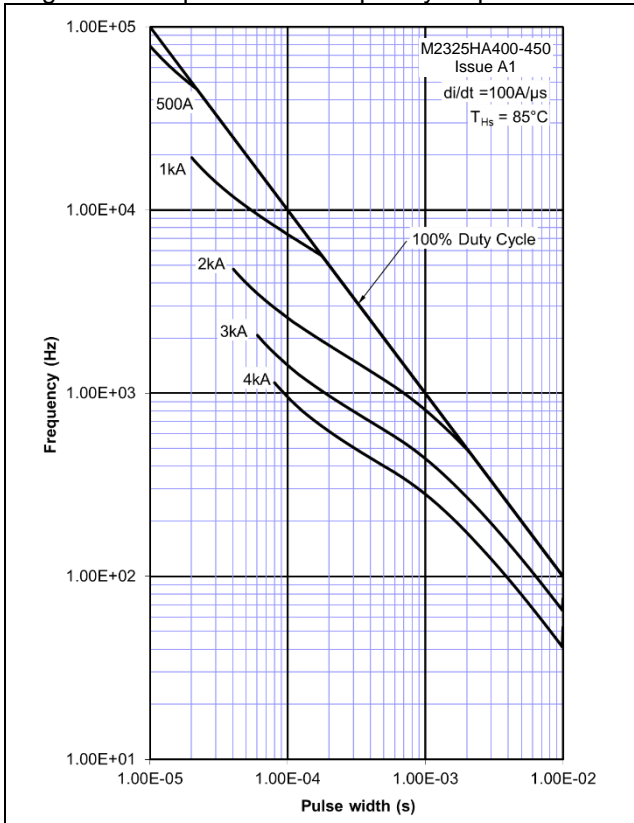


Figure 14 - Square wave frequency vs pulse width

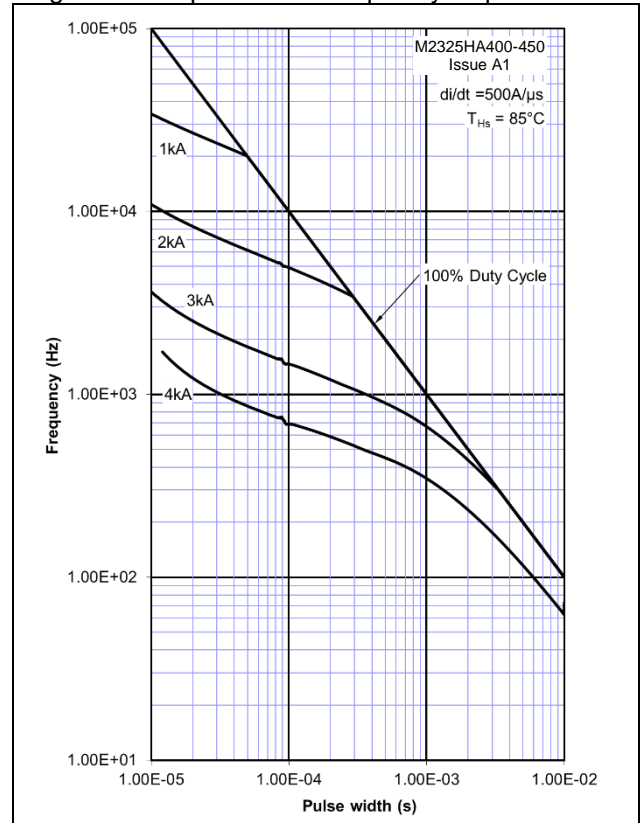


Figure 15 - Square wave energy per pulse

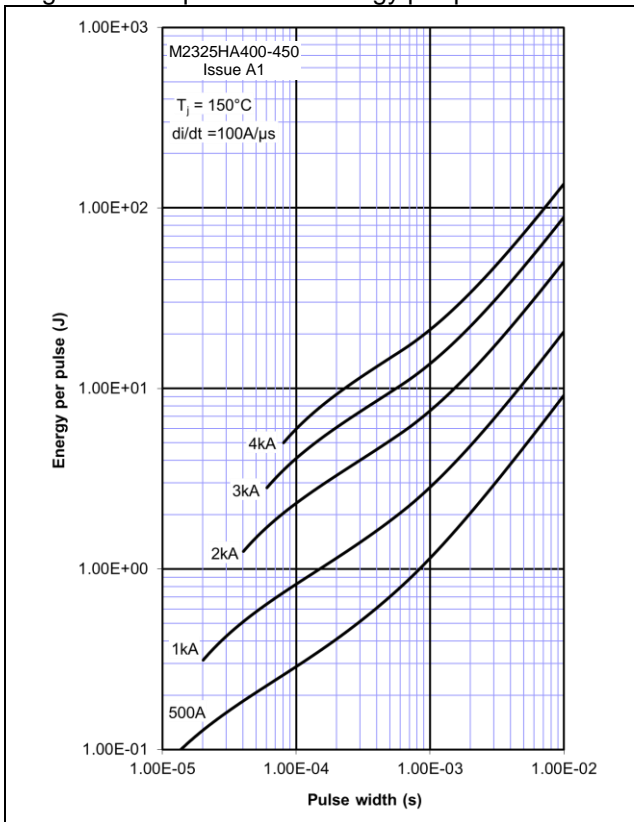


Figure 16 - Square wave energy per pulse

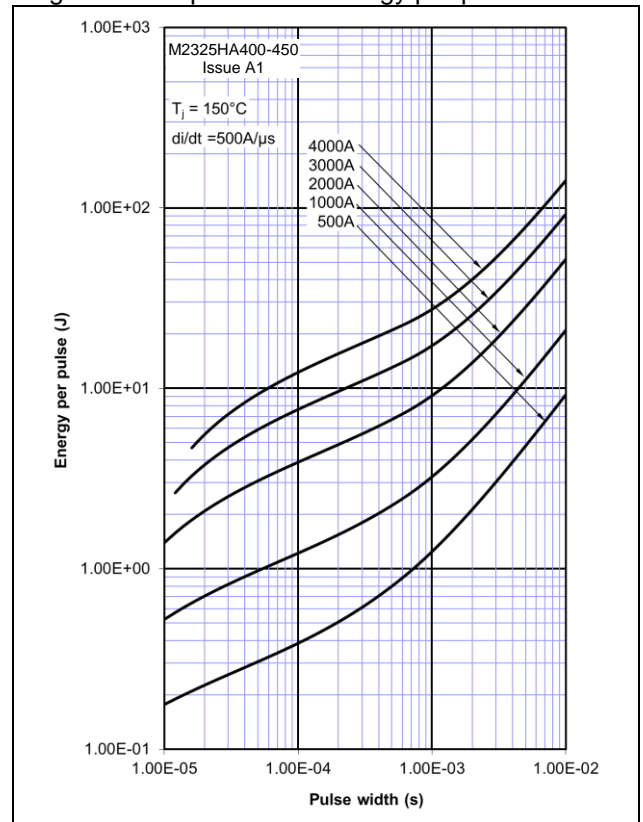


Figure 17 – Maximum surge and I²t ratings

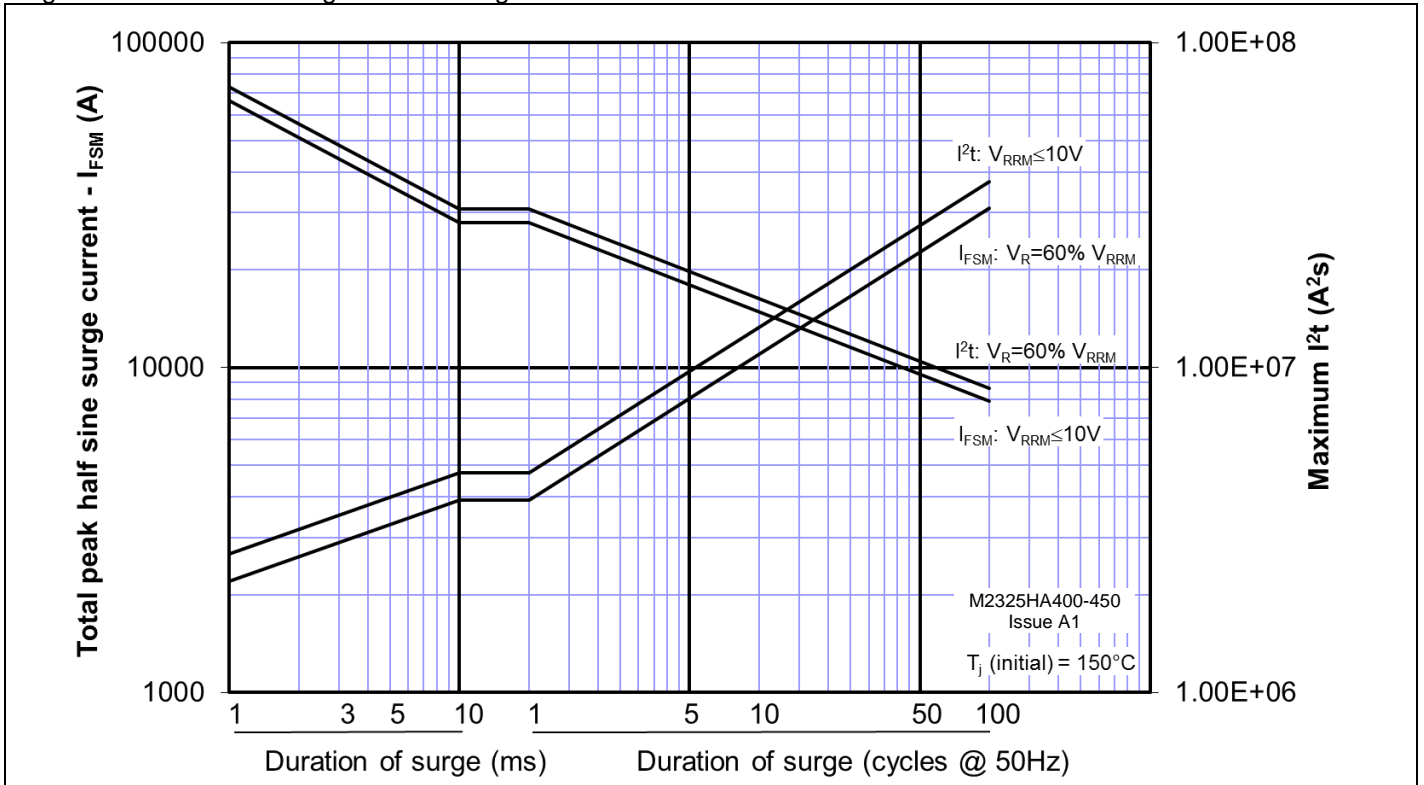
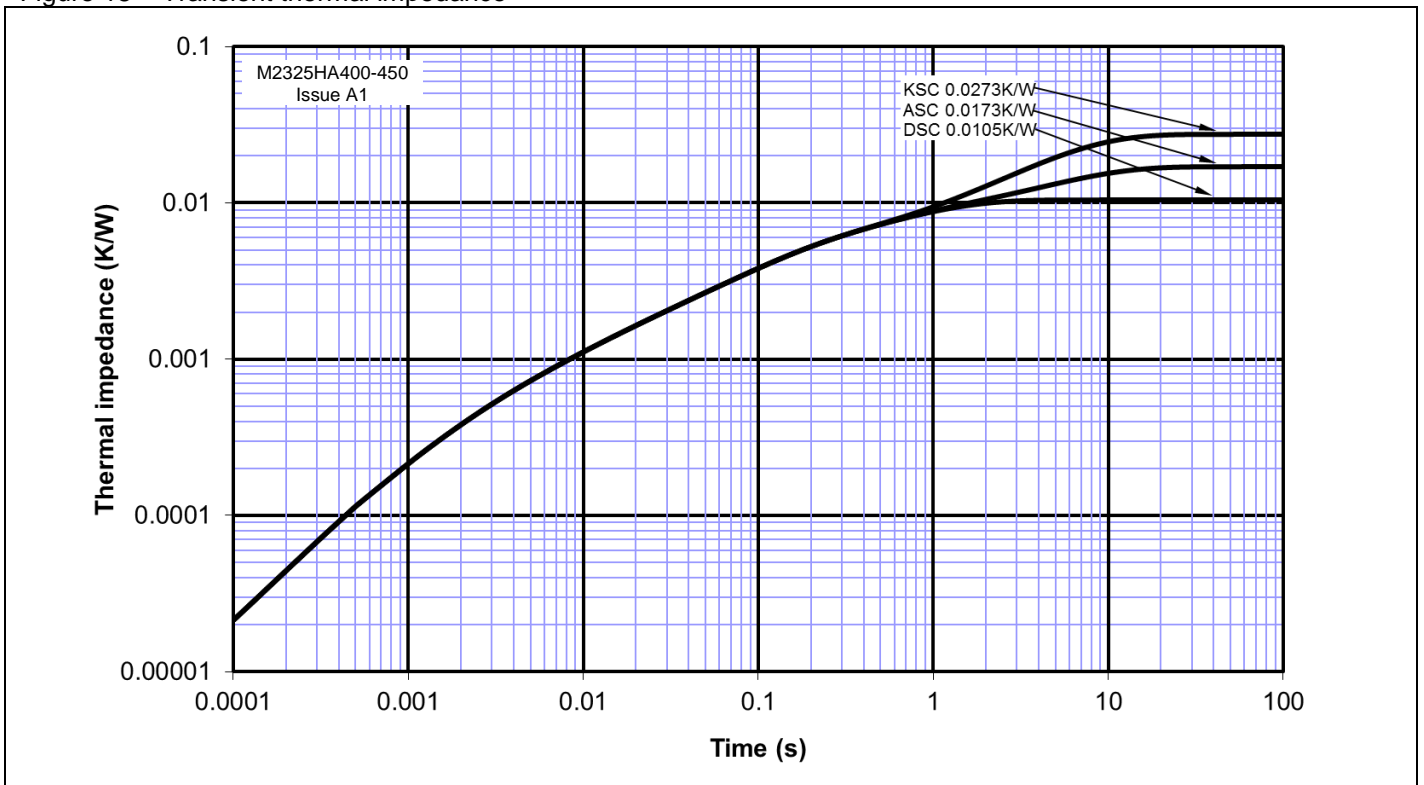
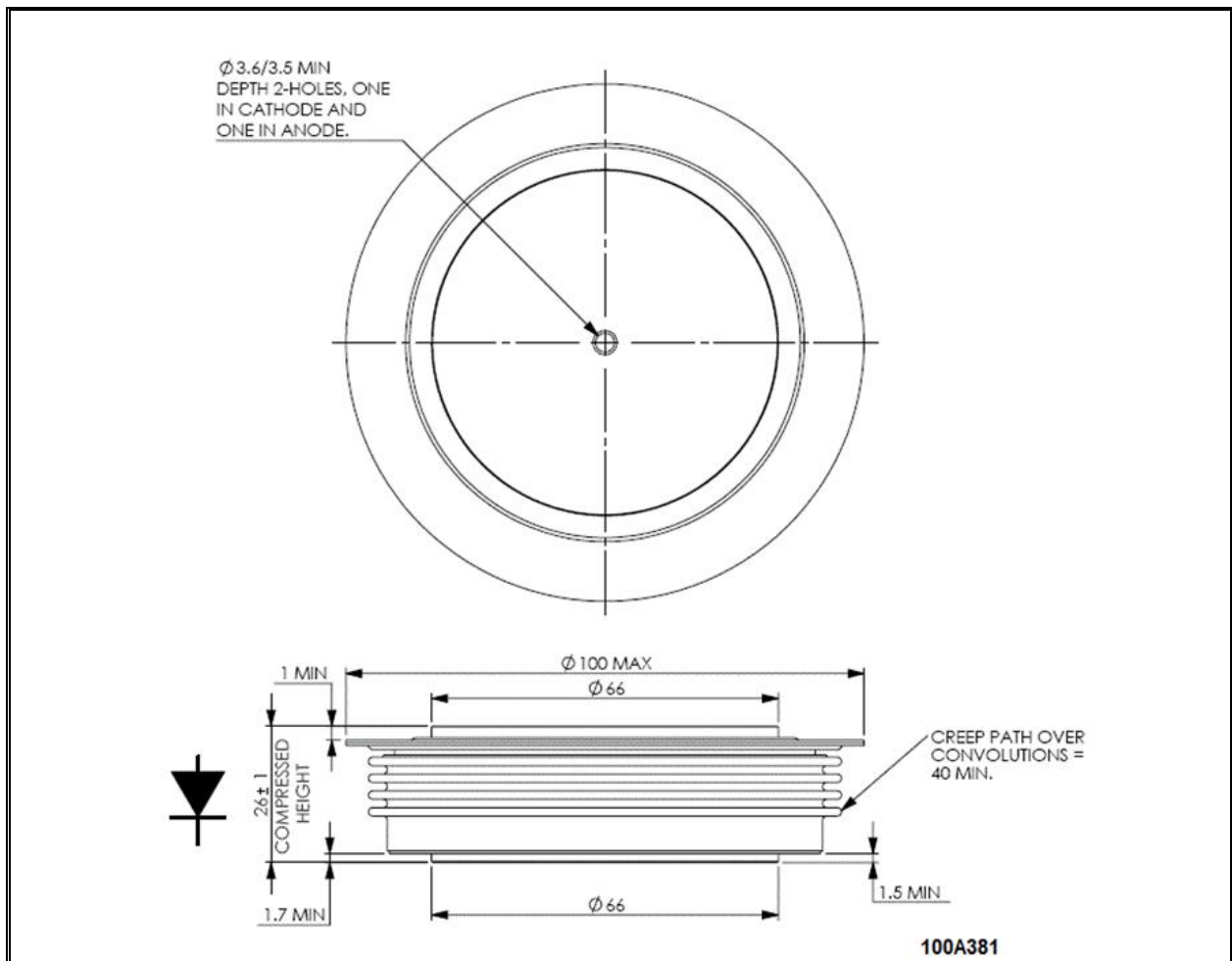


Figure 18 – Transient thermal impedance



Outline Drawing & Ordering Information

ORDERING INFORMATION

(Please quote 10 digit code as below)

M2325	HA	◆◆	0
Fixed Type Code	Outline code HA=26.5mm height	Voltage code $V_{DRM}/100$ 40 & 45	Fixed code

 Order code: M1583VF450 – 4500V V_{RRM} , 26.5mm clamp height capsule.

IXYS Semiconductor GmbH
 Edisonstraße 15
 D-68623 Lampertheim
 Tel: +49 6206 503-0
 Fax: +49 6206 503-627
 E-mail: marcom@ixys.de



IXYS UK Westcode Ltd
 Langley Park Way, Langley Park,
 Chippenham, Wiltshire, SN15 1GE.
 Tel: +44 (0)1249 444524

IXYS Corporation
 3540 Bassett Street
 Santa Clara CA 95054 USA
 Tel: +1 (408) 982 0700
 Fax: +1 (408) 496 0670
 E-mail: sales@ixys.net

www.littelfuse.com
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IXYS Long Beach Inc
 2500 Mira Mar Ave,
 Long Beach CA 90815
 Tel: +1 (562) 296 6584
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 E-mail: service@ixyslongbeach.com

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